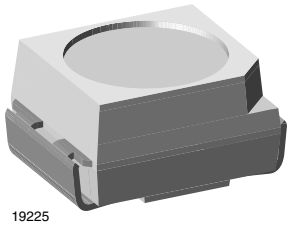
Power SMD LED PLCC-2


19225

FEATURES

- SMD LED with exceptional brightness
- Luminous intensity categorized
- Compatible with automatic placement equipment
- EIA and ICE standard package
- Compatible with IR reflow, vapor phase and wave solder processes according to CECC 00802 and J-STD-020C
- Available in 8 mm tape
- Low profile package
- Non-diffused lens: excellent for coupling to light pipes and backlighting
- Low power consumption
- Luminous intensity ratio in one packaging unit $I_{Vmax}/I_{Vmin} \leq 1.6$
- Lead (Pb)-free device
- Preconditioning: acc. to JEDEC level 2a
- Component in accordance to RoHS 2002/95/EC and WEEE 2002/96/EC
- ESD-withstand voltage: up to 2 kV according to JESD22-A114-B

DESCRIPTION

The package of the VLM.G33.. is the PLCC-2.

It consists of a lead frame which is embedded in a white thermoplast. The reflector inside this package is filled up with clear epoxy.

PRODUCT GROUP AND PACKAGE DATA

- Product group: LED
- Package: SMD PLCC-2
- Product series: power
- Angle of half intensity: ± 60°

APPLICATIONS

- Automotive: backlighting in dashboards and switches
- Telecommunication: indicator and backlighting in telephone and fax
- Indicator and backlight for audio and video equipment
- Indicator and backlight in office equipment
- Flat backlight for LCDs, switches and symbols
- General use

PARTS TABLE

PART	COLOR, LUMINOUS INTENSITY	TECHNOLOGY
VLMPG33N1P2-GS08	Pure green, I_V = (28 to 71) mcd	AlInGaP on GaAs
VLMPG33N1P2-GS18	Pure green, I_V = (28 to 71) mcd	AlInGaP on GaAs
VLMYG33P1Q2-GS08	Yellow green, I_V = (45 to 112) mcd	AlInGaP on GaAs
VLMYG33P1Q2-GS18	Yellow green, I_V = (45 to 112) mcd	AlInGaP on GaAs

ABSOLUTE MAXIMUM RATINGS[1] VLMPG33../VLMYG33..				
PARAMETER	**TEST CONDITION**	**SYMBOL**	**VALUE**	**UNIT**
Reverse voltage[2]		V_R	5	V
DC Forward current	$T_{amb} \leq 73$ °C	I_F	50	mA
Surge forward current	$t_p \leq 10$ µs	I_{FSM}	0.2	A
Power dissipation		P_V	130	mW
Junction temperature		T_j	125	°C
Operating temperature range		T_{amb}	- 40 to + 100	°C
Storage temperature range		T_{stg}	- 40 to + 100	°C
Thermal resistance junction/ ambient	mounted on PC board (pad size > 16 mm^2)	R_{thJA}	400	K/W

Note:
[1] T_{amb} = 25 °C unless otherwise specified
[2] Driving LED in reverse direction is suitable for short term application

OPTICAL AND ELECTRICAL CHARACTERISTICS[1] VLMPG33.., PURE GREEN							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN**	**TYP**	**MAX**	**UNIT**
Luminous intensity	I_F = 30 mA	VLMPG33N1P2	I_V	28		71	mcd
Dominant wavelength	I_F = 30 mA		λ_d	555	560	565	nm
Peak wavelength	I_F = 30 mA		λ_p		565		nm
Angle of half intensity	I_F = 30 mA		φ		± 60		deg
Forward voltage	I_F = 30 mA		V_F		2	2.5	V
Reverse voltage	I_R = 10 µA		V_R	5			V
Temperature coefficient of V_F	I_F = 30 mA		TC_V		- 4		mV/K
Temperature coefficient of I_V	I_F = 30 mA		TC_I		- 0.4		%/K

Note:
[1] T_{amb} = 25 °C unless otherwise specified

OPTICAL AND ELECTRICAL CHARACTERISTICS[1] VLMYG33.., YELLOW GREEN							
PARAMETER	**TEST CONDITION**	**PART**	**SYMBOL**	**MIN**	**TYP.**	**MAX**	**UNIT**
Luminous intensity	I_F = 30 mA	VLMYG33P1Q2	I_V	45		112	mcd
Luminous flux/luminous intensity			ϕ_V/I_V		3		mlm/mcd
Dominant wavelength	I_F = 30 mA		λ_d	566		577	nm
Peak wavelength	I_F = 30 mA		λ_p				nm
Spectral bandwidth at 50 % $I_{rel\ max}$	I_F = 30 mA		$\Delta\lambda$		18		nm
Angle of half intensity	I_F = 30 mA		φ		± 60		deg
Forward voltage	I_F = 30 mA		V_F	1.7	2.0	2.5	V
Reverse voltage	I_R = 10 µA		V_R	5			V
Temperature coefficient of V_F	I_F = 30 mA		T_{CV}		- 4		mV/K
Temperature coefficient of I_V	I_F = 30 mA		T_{CI}		- 0.04		%/K

Note:
[1] T_{amb} = 25 °C unless otherwise specified

LUMINOUS INTENSITY CLASSIFICATION			
GROUP	LUMINOUS INTENSITY (MCD)		
STANDARD	OPTIONAL	MIN	MAX
L	1	11.2	14.0
	2	14.0	18.0
M	1	18.0	22.4
	2	22.4	28.0
N	1	28.0	35.5
	2	35.5	45.0
P	1	45.0	56.0
	2	56.0	71.0
Q	1	71.0	90.0
	2	90.0	112.0

Note:

Luminous intensity is tested at a current pulse duration of 25 ms and an accuracy of ± 11 %.

The above type Numbers represent the order groups which include only a few brightness groups. Only one group will be shipped on each reel (there will be no mixing of two groups on each reel).

In order to ensure availability, single brightness groups will not be orderable.

In a similar manner for colors where wavelength groups are measured and binned, single wavelength groups will be shipped on any one reel.

In order to ensure availability, single wavelength groups will not be orderable.

COLOR CLASSIFICATION				
GROUP	DOMINANT WAVELENGTH (NM)			
	PURE GREEN		YELLOW GREEN	
	MIN	MAX	MIN	MAX
0	555	559		
1	558	561		
2	560	563		
3	562	565		
4				
5			566	569
6			568	571
7			570	573
8			572	575
9			574	577

Note:

Wavelengths are tested at a current pulse duration of 25 ms and an accuracy of ± 1 nm.

CROSSING TABLE	
VISHAY	OSRAM
VLMPG33N1P2	LPT675N1P2
VLMYG33P1Q2	LGT676

TYPICAL CHARACTERISTICS

T_{amb} = 25 °C, unless otherwise specified

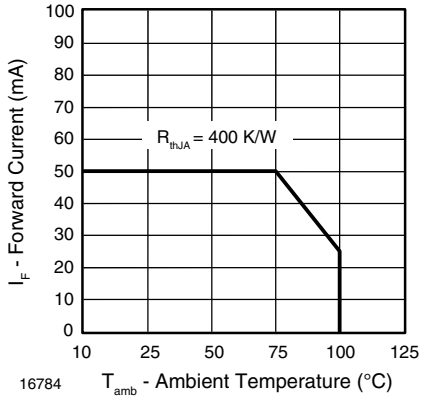


Figure 1. Forward Current vs. Ambient Temperature

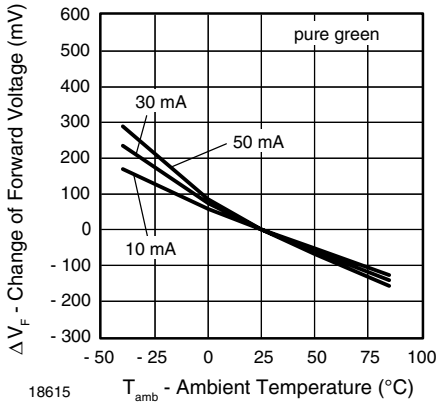


Figure 2. Change of Forward Voltage vs. Ambient Temperature

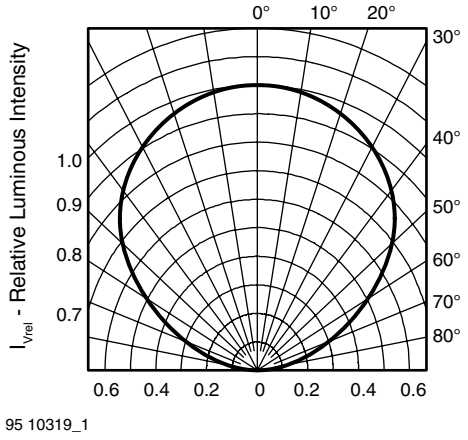


Figure 3. Rel. Luminous Intensity vs. Angular Displacement

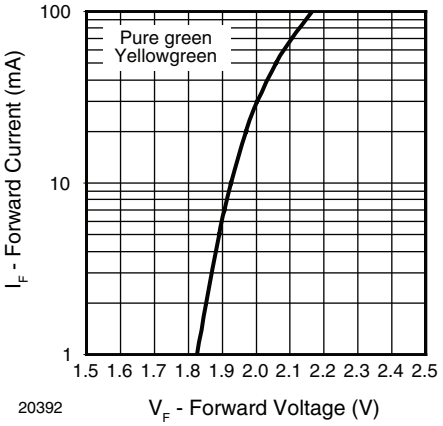


Figure 6. Forward Current vs. Forward Voltage

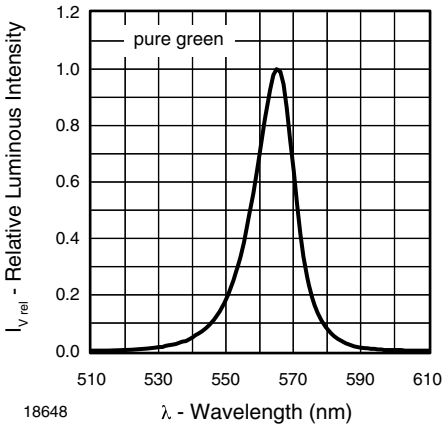


Figure 4. Relative Luminous Intensity vs. Wavelength

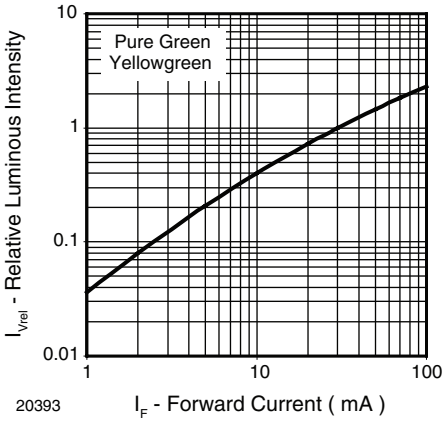


Figure 7. Rel. Luminous Intensity vs. Forward Current

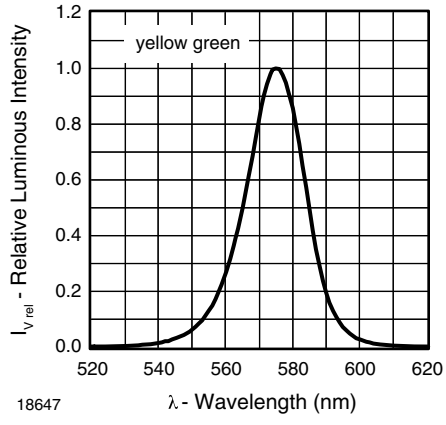


Figure 5. Relative Luminous Intensity vs. Wavelength

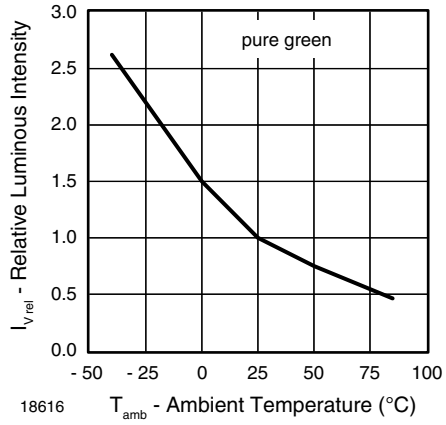


Figure 8. Rel. Luminous Intensity vs. Ambient Temperature

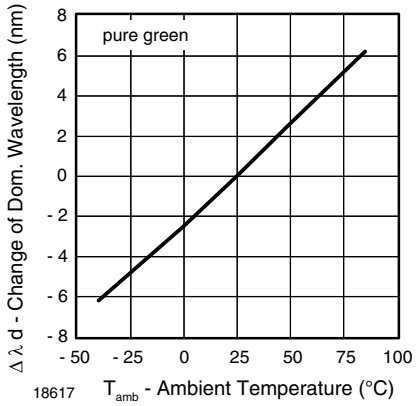


Figure 9. Change of Dominant Wavelength vs. Ambient Temperature

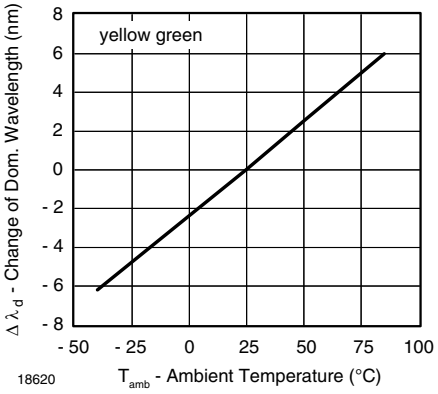


Figure 11. Change of Dominant Wavelength vs. Ambient Temperature

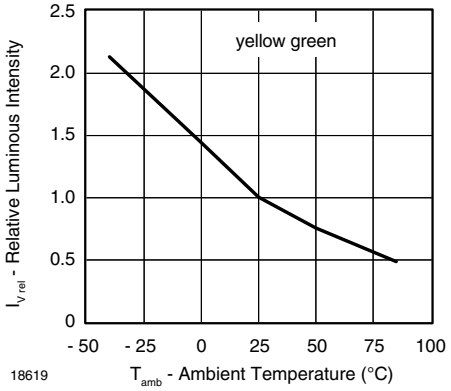
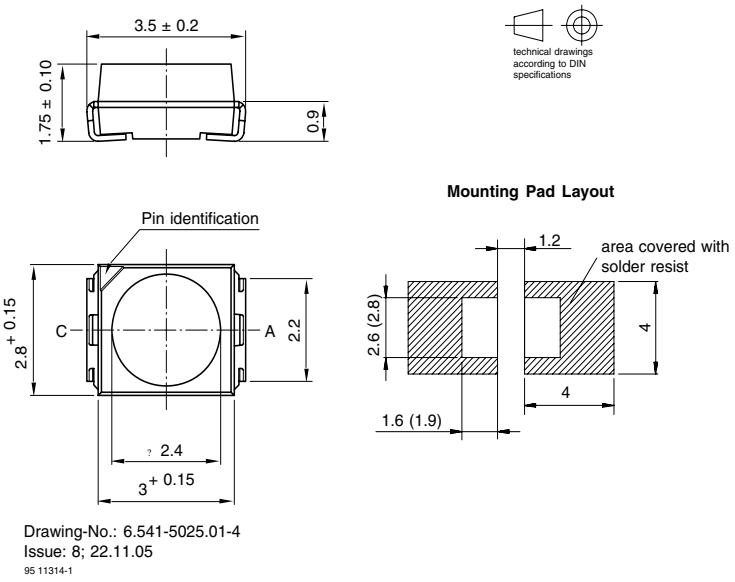


Figure 10. Rel. Luminous Intensity vs. Ambient Temperature

PACKAGE DIMENSIONS in millimeters

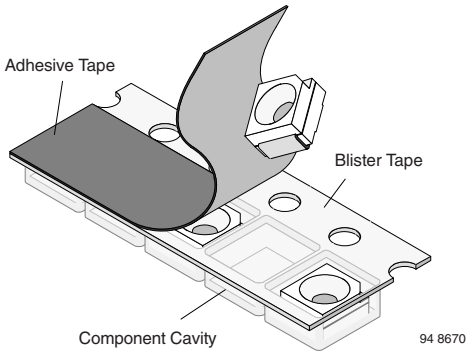


Drawing-No.: 6.541-5025.01-4
Issue: 8; 22.11.05
95 11314-1

METHOD OF TAPING/POLARITY AND TAPE AND REEL

SMD LED (VLM3 - SERIES)

Vishay's LEDs in SMD packages are available in an antistatic 8 mm blister tape (in accordance with DIN IEC 40 (CO) 564) for automatic component insertion. The blister tape is a plastic strip with impressed component cavities, covered by a top tape.



TAPING OF VLM.3..

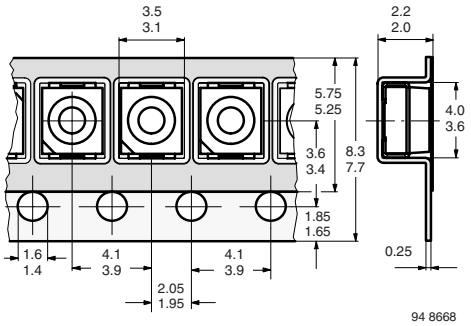


Figure 12. Tape Dimensions in mm for PLCC-2

REEL PACKAGE DIMENSION IN MM FOR SMD LEDS, TAPE OPTION GS08 (= 1500 PCS.)

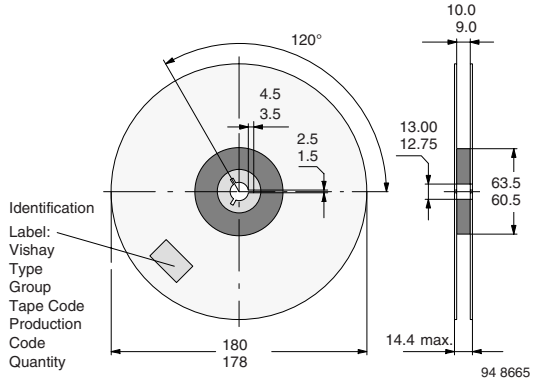


Figure 13. Reel Dimensions - GS08

REEL PACKAGE DIMENSION IN MM FOR SMD LEDS, TAPE OPTION GS18 (= 8000 PCS.) PREFERRED

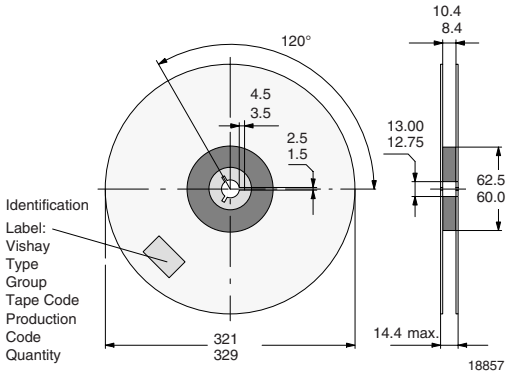


Figure 14. Reel Dimensions - GS18

SOLDERING PROFILE

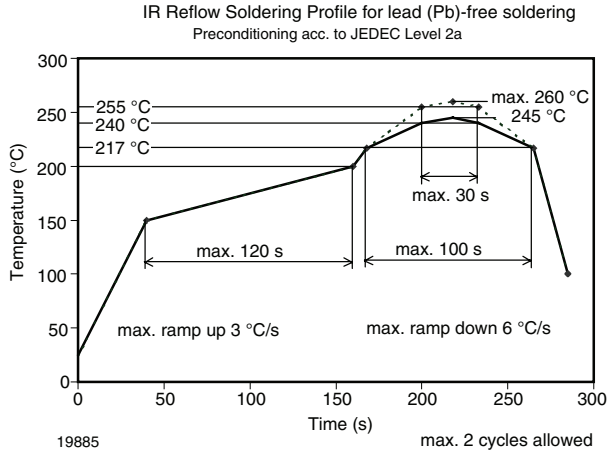


Figure 15. Vishay Leadfree Reflow Soldering Profile (acc. to J-STD-020C)

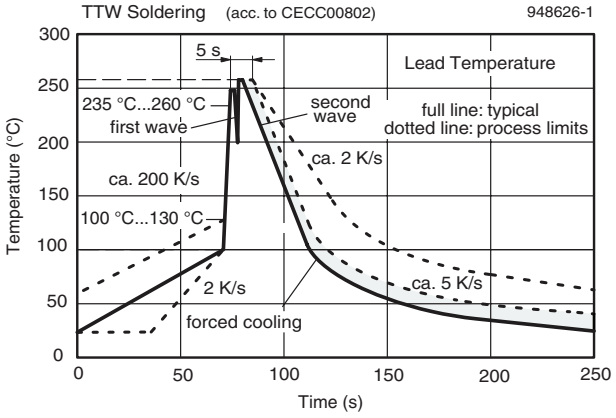
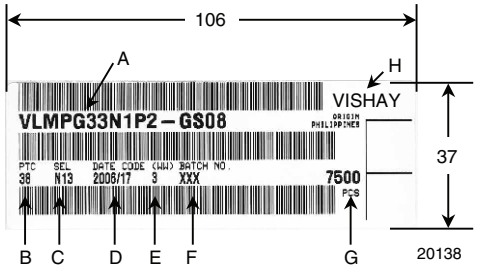


Figure 16. Double Wave Soldering of Opto Devices (all Packages)

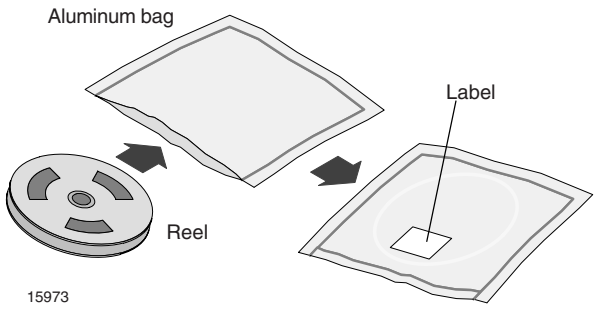
BAR CODE PRODUCT LABEL



A) Type of component
B) Manufacturing plant
C) SEL - selection code (bin):
e.g.: N1 = code for luminous intensity group
3 = code for color group
D) Date code year/week
E) Day code (e.g. 3: Wednesday)
F) Batch no.
G) Total quantity
H) Company code

DRY PACKING

The reel is packed in an anti-humidity bag to protect the devices from absorbing moisture during transportation and storage.



FINAL PACKING

The sealed reel is packed into a cardboard box. A secondary cardboard box is used for shipping purposes.

RECOMMENDED METHOD OF STORAGE

Dry box storage is recommended as soon as the aluminium bag has been opened to prevent moisture absorption. The following conditions should be observed, if dry boxes are not available:

- Storage temperature 10 °C to 30 °C
- Storage humidity ≤ 60 % RH max.

After more than 672 h under these conditions moisture content will be too high for reflow soldering.

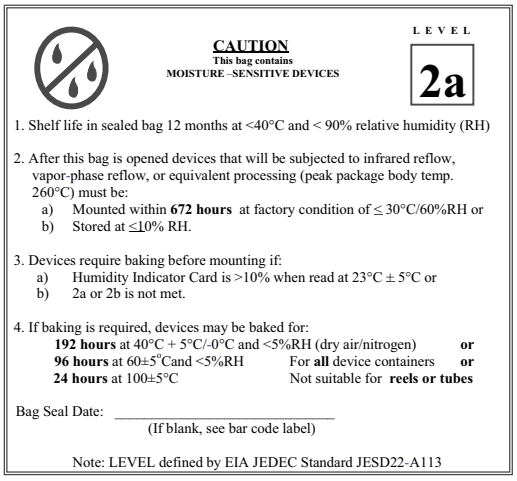
In case of moisture absorption, the devices will recover to the former condition by drying under the following condition:

192 h at 40 °C + 5 °C/ - 0 °C and < 5 % RH (dry air/ nitrogen) or

96 h at 60 °C + 5 °C and < 5 % RH for all device containers or

24 h at 100 °C + 5 °C not suitable for reel or tubes.

An EIA JEDEC standard JESD22-A112 level 2a label is included on all dry bags.



Example of JESD22-A112 level 2a label

ESD PRECAUTION

Proper storage and handling procedures should be followed to prevent ESD damage to the devices especially when they are removed from the antistatic shielding bag. Electro-static sensitive devices warning labels are on the packaging.

VISHAY SEMICONDUCTORS STANDARD BAR CODE LABELS

The Vishay Semiconductors standard bar code labels are printed at final packing areas. The labels are on each packing unit and contain Vishay Semiconductors specific data.

OZONE DEPLETING SUBSTANCES POLICY STATEMENT

It is the policy of Vishay Semiconductor GmbH to

1. Meet all present and future national and international statutory requirements.
2. Regularly and continuously improve the performance of our products, processes, distribution and operating systems with respect to their impact on the health and safety of our employees and the public, as well as their impact on the environment.

It is particular concern to control or eliminate releases of those substances into the atmosphere which are known as ozone depleting substances (ODSs).

The Montreal Protocol (1987) and its London Amendments (1990) intend to severely restrict the use of ODSs and forbid their use within the next ten years. Various national and international initiatives are pressing for an earlier ban on these substances.

Vishay Semiconductor GmbH has been able to use its policy of continuous improvements to eliminate the use of ODSs listed in the following documents.

1. Annex A, B and list of transitional substances of the Montreal Protocol and the London Amendments respectively
2. Class I and II ozone depleting substances in the Clean Air Act Amendments of 1990 by the Environmental Protection Agency (EPA) in the USA
3. Council Decision 88/540/EEC and 91/690/EEC Annex A, B and C (transitional substances) respectively.

Vishay Semiconductor GmbH can certify that our semiconductors are not manufactured with ozone depleting substances and do not contain such substances.

Vishay Semiconductor GmbH, P.O.B. 3535, D-74025 Heilbronn, Germany

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Адрес: 105318, г.Москва, ул.Щербаковская д.3, офис 1107

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http://moschip.ru/get-element

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В нашем ассортименте представлены ведущие мировые производители активных и пассивных электронных компонентов.

Нашей специализацией является поставка электронной компонентной базы двойного назначения, продукции таких производителей как XILINX, Intel (ex.ALTERA), Vicor, Microchip, Texas Instruments, Analog Devices, Mini-Circuits, Amphenol, Glenair.

Сотрудничество с глобальными дистрибьюторами электронных компонентов, предоставляет возможность заказывать и получать с международных складов практически любой перечень компонентов в оптимальные для Вас сроки.

На всех этапах разработки и производства наши партнеры могут получить квалифицированную поддержку опытных инженеров.

Система менеджмента качества компании отвечает требованиям в соответствии с ГОСТ Р ИСО 9001, ГОСТ РВ 0015-002 и ЭС РД 009

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